

A Compact 300-GHz Receiver for Wireless Communications of Tens of Gigabits per Second

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Compact 300-GHz Receiver



Background

Issues and developed technologies:

- Devices (InP HEMTs)
- ICs (low-noise amplifier, detector, IF amplifier)
- Packaging
- Demonstration
- Summary

THz Wave



- Not allocated above 275 GHz
- 10-100 GHz bandwidth (BW) usable
- 100 Gb/s+ possible with simple modem
- Large atmospheric attenuation



THz Use Cases



Short-range service
Data downloader
Data exchanger

Data center



Data downloader

Fixed wireless service



Front haul (FH) for cellular

Receiver Challenges for THz Downloader



Compact module with small antenna

- High-f_{max} device
- Low-noise amplifier (LNA)
- Wide-band detector (DET)
- Low-loss compact packaging



Low-noise THz Device Technology

75-nm InP HEMT

- Cavity structure
- f_T / f_{max}: 320 GHz / 660 GHz
- NF_{min} : 0.71 dB @94 GHz, 300K



InP-HEMT Low-noise Amplifier (LNA)



Common-gate architecture for high gain and wide BW NF: 9.8 dB @300 GHz



Wide-band Detector

- InP HEMT Schottky diode
- Wide-band differential IF amplifier
- All Integrated on 1 chip



Low-loss Compact Packaging

Expanded flip-chip mounting to THz-band for the first time

- Employing low-loss polyimide substrate
- Compact built-in horn antenna: 16 dBi
- Cubic capacity: 0.75 cm³

Receiver module

Downloader Demo

Collaboration with NTT, NICT, and FUJITSU
Physical rate: 20 Gb/s, effective rate: 16 Gb/s

Summary

Compact THz receiver for 20-Gb/s data transmission

- 75-nm InP HEMT f_{max}: 660 GHz
- 1-chip receiver IC
- Low-loss flip-chip mounting technique
- Cubic volume: 0.75 cm³

Instantaneous downloader demo

- 300 GHz, 20 Gb/s
- Only 2 sec. for 1-DVD data (4GB)

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